

Photointerrupter, Small type



Absolute maximum ratings (Ta=25°C)

| Parameter             |                      | Symbol    | Limits      | Unit |
|-----------------------|----------------------|-----------|-------------|------|
| Input (LED)           | Forward current      | $I_F$     | 50          | mA   |
|                       | Reverse voltage      | $V_R$     | 5           | V    |
|                       | Power dissipation    | $P_D$     | 80          | mW   |
| Output (photo IC)     | Power supply voltage | $V_{CC}$  | 7           | V    |
|                       | Output current       | $I_O$     | 10          | mA   |
|                       | Power dissipation    | $P_D$     | 80          | mW   |
| Operating temperature |                      | $T_{opr}$ | -20 to +60  | °C   |
| Storage temperature   |                      | $T_{stg}$ | -40 to +100 | °C   |

Applications

Optical control equipment

Features

- 1) Small slit width (0.3mm) for high precision.
- 2) Fast response.
- 3) Built-in visible light filter.

Electrical and optical characteristics (Ta=25°C)

| Parameter                    |                                    | Symbol                            | Min.      | Typ. | Max. | Unit    | Conditions  |                                     |
|------------------------------|------------------------------------|-----------------------------------|-----------|------|------|---------|---|-------------------------------------|
| Input characteristics        | Forward voltage                    | $V_F$                             | -         | 1.1  | 1.3  | V       | $I_F=10mA$  |                                     |
|                              | Reverse current                    | $I_R$                             | -         | -    | 10   | $\mu A$ | $V_R=5V$  |                                     |
| Output characteristics       | Power supply voltage               | $V_{CC}$                          | 2.0       | -    | 7.0  | V       | -   |                                     |
|                              | Output low level voltage           | $V_{OL}$                          | -         | 0.08 | 0.35 | V       | $V_{CC}=3V, I_{OL}=2mA$   |                                     |
|                              | Output high level voltage          | $V_{OH}$                          | 2.8       | -    | 3.0  | V       | $V_{CC}=3V, I_F=0mA$  |                                     |
|                              | Low level power supply current     | $I_{CCL}$                         | -         | 0.35 | 1.5  | mA      | $V_{CC}=3V, I_F=5mA$  |                                     |
|                              | High level power supply current    | $I_{CCH}$                         | -         | 0.35 | 1.5  | mA      | $V_{CC}=3V, I_F=0mA$  |                                     |
| Transfer characteristics     | High → Low Threshold input current | $I_{FHL}$                         | 0.25      | -    | 2.5  | mA      | $V_{CC}=3V$   |                                     |
|                              | Hysteresis                         | $I_{FLH} / I_{FHL}$               | 0.4       | 0.7  | 0.9  | -       | $V_{CC}=3V$   |                                     |
|                              | Response time                      | Low → High Propagation delay time | $t_{PLH}$ | -    | 22   | 66      | $\mu s$   | $V_{CC}=3V, I_F=5mA, R_L=100\Omega$ |
|                              |                                    | High → Low Propagation delay time | $t_{PHL}$ | -    | 5.5  | 16      |   |                                     |
|                              |                                    | Rise time                         | $t_r$     | -    | 5    | 15      |   |                                     |
|                              |                                    | Fall time                         | $t_f$     | -    | 0.05 | 0.15    |   |                                     |
| Infrared light emitter diode | Cut-off frequency                  | $f_c$                             | -         | 1    | -    | MHz     | $I_F=50mA$<br>* Non-coherent Infrared light emitting diode used.  |                                     |
|                              | Peak light emitting wavelength     | $\lambda_P$                       | -         | 950  | -    | nm      |   |                                     |
| Photo IC                     | Response time                      | $t_r$                             | -         | 5    | 15   | $\mu s$ | $V_{CC}=3V, I_F=5mA, R_L=100\Omega$<br>* This product is not designed to be protected against electromagnetic wave. |                                     |
|                              |                                    | $t_f$                             | -         | 0.05 | 0.15 |         |   |                                     |

Electrical and optical characteristics curves

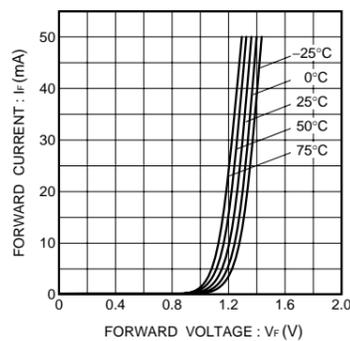


Fig.1 Forward current vs. forward voltage

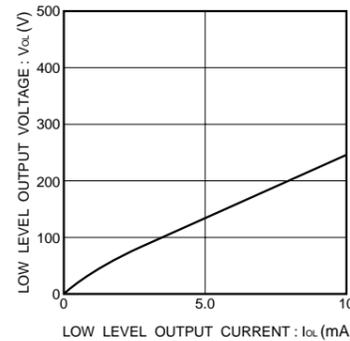


Fig.2 Low level output voltage vs. low level output current

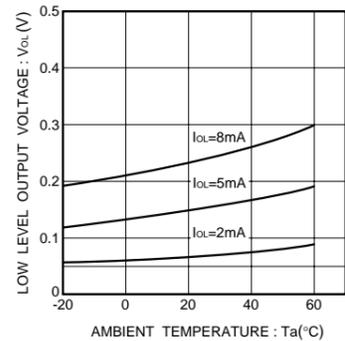


Fig.3 Low level output voltage vs. ambient temperature

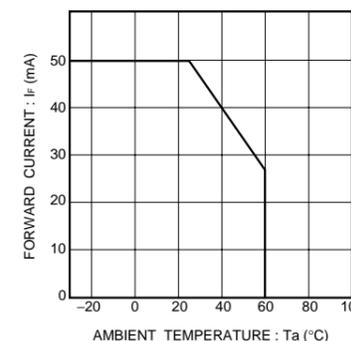


Fig.7 Forward current falloff

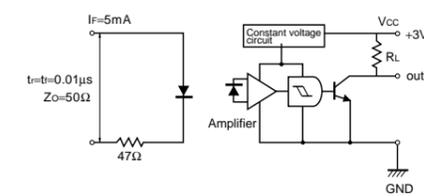


Fig.8 Response time measurement circuit

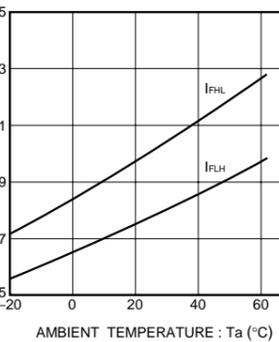
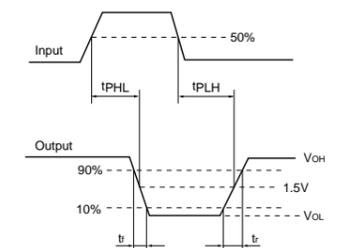


Fig.4 Threshold input current vs. ambient temperature

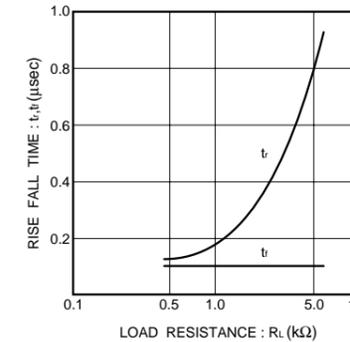


Fig.5 Response time vs. load resistance

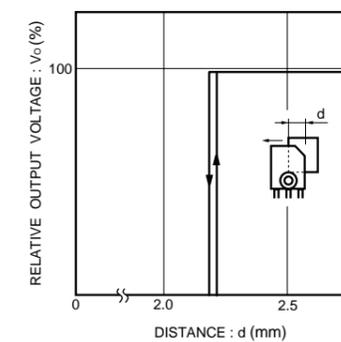
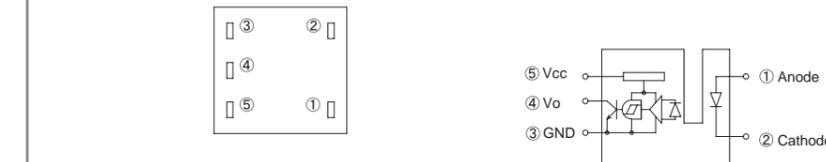


Fig.6 Relative output voltage vs. distance characteristics



- Notes:
1. Unspecified tolerance shall be  $\pm 0.2$ .
  2. Dimension in parenthesis show for reference.

External dimensions (Unit : mm)

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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

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